

In The Claims:

The listing of claims will replace all prior versions, and listings, of claims in the application.

Listing of Claims:

1. (currently amended) A termination circuit for a transmission line, the termination circuit comprising:

an input node receiving an input signal over the transmission line;

an NMOS pull-down transistor ~~a pull-down circuit~~ coupled between the input node and a first reference voltage wherein the ~~pull-down circuit~~ NMOS pull-down transistor is configured to provide an electrical path between the first reference voltage and the input node responsive to the input signal having a first voltage level; and

a PMOS pull-up transistor ~~pull-up circuit~~ coupled between the input node and a second reference voltage wherein the PMOS pull-up transistor ~~pull-up circuit~~ is configured to provide an electrical path between the second reference voltage and the input node responsive to the input signal having a second voltage level, wherein the first reference voltage is less than the second reference voltage and wherein the first voltage level is greater than the second voltage level;

wherein the NMOS pull-down transistor ~~pull-down circuit~~ maintains the electrical path between the first reference voltage and the input node while the input signal is maintained steady state at the first voltage level;

wherein the PMOS pull-up transistor ~~pull-up circuit~~ maintains the electrical path between the second reference voltage and the input node while the input signal is maintained steady state at the second voltage level.

2. (original) A termination circuit according to Claim 1 wherein the first voltage level comprises a logic high voltage level and wherein the second voltage level comprises a logic low voltage level.

3. (original) A termination circuit according to Claim 1 wherein the first reference voltage comprises a ground voltage and the second reference voltage comprises a supply voltage.

4. (currently amended) A termination circuit according to Claim 1 wherein:
the NMOS pull-down transistor ~~pull-down circuit~~ is further configured to block the electrical path between the first reference voltage and the input node responsive to the input signal having the second voltage level; and

the PMOS pull-up transistor ~~pull-up circuit~~ is further configured to block the electrical current path between the second reference voltage and the input node responsive to the input signal having the first voltage level.

5. (currently amended) A termination circuit according to Claim 4 wherein the NMOS pull-down transistor ~~pull-down~~ and the PMOS pull-up transistor ~~pull-up circuits~~ are further configured to provide electrical paths between the input node and both of the first and second reference voltages at a same time during a transition of the input signal between the first and second voltage levels.

6. (currently amended) A termination circuit according to Claim 1 further comprising:
~~wherein the pull-down circuit includes~~

a pull-down resistor ~~and a pull-down transistor~~ coupled in series with the NMOS pull-down transistor between the input node and the first reference voltage.

7. (currently amended) ~~A termination circuit according to Claim 6~~ A termination circuit for a transmission line, the termination circuit comprising:

an input node receiving an input signal over the transmission line;

a pull-down circuit coupled between the input node and a first reference voltage wherein the pull-down circuit is configured to provide an electrical path between the first reference voltage and the input node responsive to the input signal having a first voltage level; and

a pull-up circuit coupled between the input node and a second reference voltage wherein the pull-up circuit is configured to provide an electrical path between the second reference voltage and the input node responsive to the input signal having a second voltage level, wherein the first reference voltage is less than the second reference voltage and wherein the first voltage level is greater than the second voltage level;

wherein the pull-down circuit maintains the electrical path between the first reference voltage and the input node while the input signal is maintained steady state at the first voltage level;

wherein the pull-up circuit maintains the electrical path between the second reference voltage and the input node while the input signal is maintained steady state at the second voltage level;

wherein the pull-down circuit includes a pull-down resistor and a pull-down transistor coupled in series between the input node and the first reference voltage;

wherein the pull-down circuit includes a first input resistor connected between the input node and a control electrode of the pull-down transistor.

8. (original) A termination circuit according to Claim 7 wherein the pull-down transistor comprises an NMOS transistor.

9. (currently amended) A termination circuit according to Claim 1 further comprising:
~~wherein the pull-up circuit includes~~

a pull-up resistor and a pull-up transistor coupled in series with the PMOS pull-up transistor between the input node and the second reference voltage.

10. (currently amended) ~~A termination circuit according to Claim 9~~ A termination circuit for a transmission line, the termination circuit comprising:

an input node receiving an input signal over the transmission line;

a pull-down circuit coupled between the input node and a first reference voltage wherein the pull-down circuit is configured to provide an electrical path between the first reference voltage and the input node responsive to the input signal having a first voltage level; and

a pull-up circuit coupled between the input node and a second reference voltage wherein the pull-up circuit is configured to provide an electrical path between the second reference voltage and the input node responsive to the input signal having a second voltage level, wherein the first reference voltage is less than the second reference voltage and wherein the first voltage level is greater than the second voltage level;

wherein the pull-down circuit maintains the electrical path between the first reference voltage and the input node while the input signal is maintained steady state at the first voltage level;

wherein the pull-up circuit maintains the electrical path between the second reference voltage and the input node while the input signal is maintained steady state at the second voltage level;

wherein the pull-up circuit includes a pull-up resistor and a pull-up transistor coupled in series between the input node and the second reference voltage;

wherein the pull-up circuit includes a pull-up input resistor connected between the input node and a control electrode of the pull-up transistor.

11. (original) A termination circuit according to Claim 10 wherein the pull-up transistor comprises a PMOS transistor.

12. (currently amended) A termination circuit according to Claim 1 further comprising:
~~wherein the pull-down circuit includes~~

~~a pull-down resistor and a pull-down transistor~~ coupled in series with the NMOS pull-down transistor between the input node and the first reference voltage; and ~~, and wherein the pull-up circuit includes~~

~~a pull-up resistor and a pull-up transistor~~ coupled in series with the PMOS pull-up transistor between the input node and the second reference voltage.

13. (currently amended) ~~A termination circuit according to Claim 12~~ A termination circuit for a transmission line, the termination circuit comprising:

an input node receiving an input signal over the transmission line;

a pull-down circuit coupled between the input node and a first reference voltage wherein the pull-down circuit is configured to provide an electrical path between the first reference voltage and the input node responsive to the input signal having a first voltage level; and

a pull-up circuit coupled between the input node and a second reference voltage wherein the pull-up circuit is configured to provide an electrical path between the second reference voltage and the input node responsive to the input signal having a second voltage level, wherein the first reference voltage is less than the second reference voltage and wherein the first voltage level is greater than the second voltage level;

wherein the pull-down circuit maintains the electrical path between the first reference voltage and the input node while the input signal is maintained steady state at the first voltage level;

wherein the pull-up circuit maintains the electrical path between the second reference voltage and the input node while the input signal is maintained steady state at the second voltage level;

wherein the pull-down circuit includes a pull-down resistor and a pull-down transistor coupled in series between the input node and the first reference voltage, and wherein the pull-up circuit includes a pull-up resistor and a pull-up transistor coupled in series between the input node and the second reference voltage;

wherein the pull-down circuit includes a first input resistor connected between the input node and a control electrode of the pull-down transistor, and wherein the pull-up circuit includes a pull-up resistor and a pull-up transistor coupled in series between the input node and the second reference voltage.

14. (original) A termination circuit according to Claim 13 wherein the pull-down transistor comprises an NMOS transistor, and wherein the pull-up transistor comprises a PMOS transistor.

15. (canceled).

16. (canceled).

17. (canceled).

18. (canceled).

19. (canceled).

20. (previously presented) A termination circuit which reduces ringing and dynamic current, which occur when an input signal is transmitted through a transmission line to an input node, the termination circuit comprising:

a first switching unit which includes a first termination resistor used to form a path for current flow between the input node and a first voltage when a voltage level of the input signal is at a first level; and

a second switching unit which includes a second termination resistor used to form a path for current flow between the input node and a second voltage when the voltage level of the input signal is at a second level,

wherein the first voltage is less than the second voltage,

wherein the first level is high and the second level is low,

wherein termination resistance of the first and second switching units are maintained level to a resistance of the transmission line when the voltage level of the input signal is changed.

21. (previously presented) The termination circuit of claim 20, wherein the first switching unit comprises a first transistor, including a first end connected to the first voltage and a gate receiving the input signal, and the first termination resistor, which is connected between a second end of the first transistor and the input node.

22. (previously presented) The termination circuit of claim 21, wherein the first switching unit further comprises a first resistor, which is used to protect the gate of the first transistor and is positioned between the input node and the gate of the first transistor.

23. (original) The termination circuit of claim 21, wherein the first transistor is an NMOS transistor.

24. (previously presented) The termination circuit of claim 20, wherein the second switching unit comprises a second transistor, including a first end connected to the second voltage and a gate receiving the input signal, and the second termination resistor, which is connected between a second end of the second transistor and the input node.

25. (previously presented) The termination circuit of claim 24, wherein the second switching unit further comprises a second resistor, which is used to protect the gate of the second transistor and is positioned between the input node and the gate of the second transistor.

26. (original) The termination circuit of claim 25, wherein the second transistor is a PMOS transistor.

27. (original) The termination circuit of claim 20, wherein a voltage level of the first voltage is the same as a voltage level of a ground voltage, and a voltage level of the second voltage is the same as a voltage level of a supply voltage.

Claim 28 (cancelled).

29. (original) The termination circuit of claim 20, wherein the termination circuit is mounted in a semiconductor chip.

30. (previously presented) A termination circuit which reduces ringing and dynamic current which occur when an input signal is transmitted through a transmission line to an input node, the termination circuit comprising:

a first termination unit which includes a first termination resistor coupled between the input node and a ground voltage allowing impedance matching at the input node to be performed by using the ground voltage when a voltage level of the input signal at the input node is high; and

a second termination unit which includes a second termination resistor coupled between the input node and a supply voltage allowing impedance matching at the input node to be performed by using the supply voltage when a voltage level of the input signal at the input node is low,

wherein termination resistance of the first and second termination units are maintained level to a resistance of the transmission line when the voltage level of the input signal changes.

31. (previously presented) The termination circuit of claim 30, wherein the first termination unit further comprises an NMOS transistor, including a first end connected to the ground voltage and a gate receiving the input signal, and the first termination resistor, which is connected between a second end of the NMOS transistor and the input node.

32. (previously presented) The termination circuit of claim 30, wherein the first termination unit further comprises a first resistor, which is used to protect the gate of the NMOS transistor and is positioned between the input node and the gate of the NMOS transistor.

33. (previously presented) The termination circuit of claim 30, wherein the second termination unit further comprises a PMOS transistor, including a first end connected to the

supply voltage and a gate receiving the input signal, and the second termination resistor, which is connected between a second end of the PMOS transistor and the input node.

34. (previously presented) The termination circuit of claim 33, wherein the second termination unit further comprises a second resistor, which is used to protect the gate of the PMOS transistor and is positioned between the input node and the gate of the PMOS transistor.

35. (original) The termination circuit of claim 30, wherein the termination circuit is mounted on a semiconductor chip.

36. (currently amended) A termination circuit which reduces ringing and dynamic current, which occur when an input signal is transmitted through a transmission line to an input node, the termination circuit comprising:

a pull-down unit including an NMOS pull-down transistor which prevents a voltage level at the input node from reaching a voltage level of a second voltage when a voltage level of the input signal at the input node is at a first level; and

a pull-up unit including a PMOS pull-up transistor which prevents a voltage level at the input node from reaching a voltage level of a first voltage when a voltage level of the input signal at the input node is at a second level;

wherein a voltage level of the first voltage is the same as a voltage level of a ground voltage, and a voltage level of the second voltage is the same as a voltage level of a supply voltage,

wherein the first level is high, and the second level is low.

37. (currently amended) The termination circuit of claim 36, ~~the pull-down unit further comprises: wherein the~~ an NMOS pull-down transistor including includes a first end connected to the first voltage and a gate receiving the input signal, ~~and ; and wherein the pull-down unit further includes~~ a first termination resistor which is connected between a second end of the NMOS pull-down transistor and the input node.

38. (currently amended) ~~The termination circuit of claim 37,~~ A termination circuit which reduces ringing and dynamic current, which occur when an input signal is transmitted through a transmission line to an input node, the termination circuit comprising:

a pull-down unit which prevents a voltage level at the input node from reaching a voltage level of a second voltage when a voltage level of the input signal at the input node is at a first level; and

a pull-up unit which prevents a voltage level at the input node from reaching a voltage level of a first voltage when a voltage level of the input signal at the input node is at a second level,

wherein a voltage level of the first voltage is the same as a voltage level of a ground voltage, and a voltage level of the second voltage is the same as a voltage level of a supply voltage,

wherein the first level is high, and the second level is low;

wherein the pull-down unit further comprises an NMOS transistor including a first end connected to the first voltage and a gate receiving the input signal, and a first termination resistor which is connected between a second end of the NMOS transistor and the input node;

wherein the pull-down unit further comprises a first resistor, which is used to protect the gate of the NMOS transistor, between the input node and the gate of the NMOS transistor.

39. (currently amended) ~~The termination circuit of claim 36, wherein the pull-up unit further comprises a~~ the PMOS pull-up transistor including includes a first end connected to the second voltage and a gate to receiving the input signal, and ; and wherein the pull-up unit further includes a second termination resistor which is connected between a second end of the PMOS pull-up transistor and the input node.

40. (previously presented) ~~The termination circuit of claim 39,~~ A termination circuit which reduces ringing and dynamic current, which occur when an input signal is transmitted through a transmission line to an input node, the termination circuit comprising:

a pull-down unit which prevents a voltage level at the input node from reaching a voltage level of a second voltage when a voltage level of the input signal at the input node is at a first level; and

a pull-up unit which prevents a voltage level at the input node from reaching a voltage level of a first voltage when a voltage level of the input signal at the input node is at a second level,

wherein a voltage level of the first voltage is the same as a voltage level of a ground voltage, and a voltage level of the second voltage is the same as a voltage level of a supply voltage,

wherein the first level is high, and the second level is low;

wherein the pull-up unit further comprises a PMOS transistor including a first end connected to the second voltage and a gate to receiving the input signal, and a second termination resistor which is connected between a second end of the PMOS transistor and the input node;

wherein the pull-up unit further comprises a second resistor, which is used to protect the gate of the PMOS transistor, between the input node and the gate of the PMOS transistor.

Claims 41-42 (cancelled).

43. (original) The termination circuit of claim 36, wherein the termination circuit is mounted in a semiconductor chip.

44. (new) A termination circuit according to Claim 1 further comprising:

a first input resistor coupled between the input node and a gate electrode of the NMOS transistor; and

a second input resistor coupled between the input node and a gate electrode of the PMOS transistor.

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45. (new) A termination circuit according to Claim 13 wherein the pull-up circuit includes a second input resistor connected between the input node and a control electrode of the pull-up transistor.